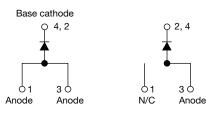


Vishay Semiconductors

Ultralow V_F Ultrafast Rectifier, 15 A FRED Pt[®]



DPAK (TO-252AA)



VS-15AWL06FN-M3

VS-15EWL06FN-M3

PRIMARY CHARACTERISTICS									
I _{F(AV)}	15 A								
V _R	600 V								
V _F at I _F	0.85 V								
t _{rr} (typ.)	60 ns								
T _J max.	175 °C								
Package	DPAK (TO-252AA)								
Circuit configuration	Single								

FEATURES

- Ultrafast recovery time, extremely low V_F and soft recovery
- 175 °C maximum operating junction temperature
- For PFC DCM operation
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art, ultralow V_F, soft-switching hyperfast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Peak repetitive reverse voltage	V _{RRM}		600	V					
Average rectified forward current	I _{F(AV)}	T _C = 148 °C	15						
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$	180	А					
Peak repetitive forward current	I _{FM}	$T_{C} = 148 \ ^{\circ}C, f = 20 \ \text{kHz}, d = 50 \ \%$	30						
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C					

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	AMETER SYMBOL TEST CONDITIONS								
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-				
	V _F	I _F = 15 A	-	0.99	1.05	V			
Forward voltage		I _F = 15 A, T _J = 150 °C	-	0.85	0.92				
Deveres laskage surrent	I _R	$V_{\rm R} = V_{\rm R}$ rated	-	-	10				
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	120	μA					
Junction capacitance	CT	V _R = 600 V	-	11	-	pF			
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH			

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RoHS COMPLIANT HALOGEN FREE



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 \text{ A}, dI_F/dt = 10$	00 A/µs, V _R = 30 V	-	60	120				
Reverse recovery time	t _{rr}	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 1000 \text{ cm}^{-1}$	-	190	-					
Reverse recovery time		T _J = 25 °C		-	220	-	ns			
		T _J = 125 °C		-	290	-				
Deals receivers ourrent	I _{RRM}	T _J = 25 °C	l _F = 15 A dl _F /dt = 200 A/µs	-	21	-	А			
Peak recovery current		T _J = 125 °C	$V_{\rm B} = 390 \text{ V}$	-	25	-	~			
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	2.6	-				
		T _J = 125 °C		-	4	-	μC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX.									
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C				
Thermal resistance, junction to case	R _{thJC}		-	1.4	1.8	°C/W				
Thermal resistance, junction to ambient	R _{thJA}		-	-	70	0/11				
Approximate weight				0.3		g				
			0.01			oz.				
Marking device		Case style DPAK (TO-252AA)	15AWL06FN							
		Case sigle DFAR (TO-252AA)	15EWL06FN							



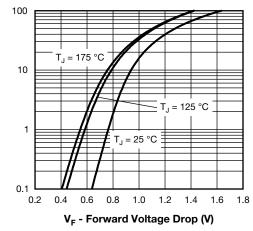


Fig. 1 - Typical Forward Voltage Drop Characteristics

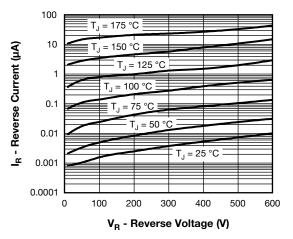


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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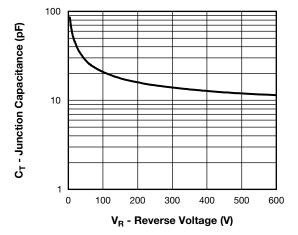


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

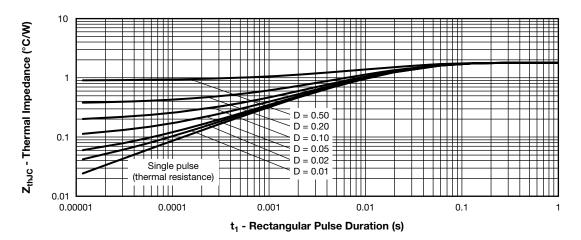
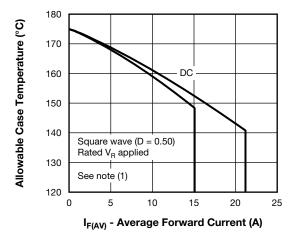
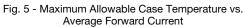


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)

20



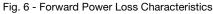


Note

Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; (1)

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{I} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

15 RMS limit D = 0.01 10 D = 0.02 D = 0.05 D = 0.10 5 D = 0.20 D = 0.50 DC 0 5 10 15 20 25 0 I_{F(AV)} - Average Forward Current (A)



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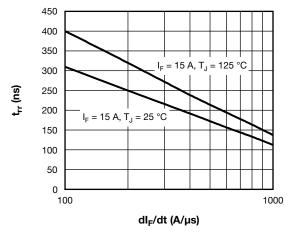


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

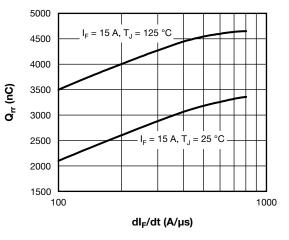


Fig. 8 - Typical Stored Charge vs. dl_F/dt

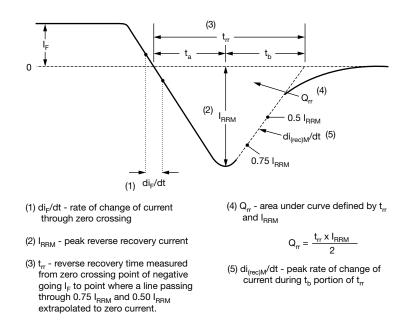


Fig. 9 - Reverse Recovery Waveform and Definitions

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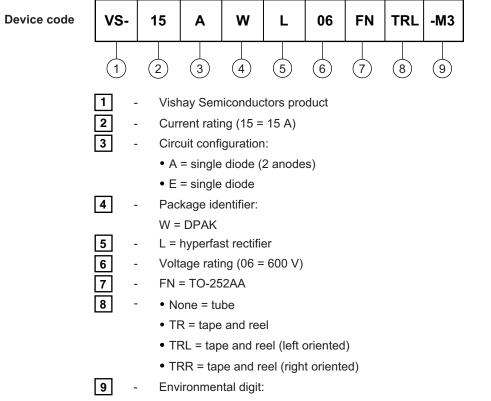
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ORDERING INFORMATION TABLE



-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-15AWL06FN-M3	75	3000	Antistatia plastia tuba						
VS-15EWL06FN-M3	75	3000	Antistatic plastic tube						
VS-15AWL06FNTR-M3	2000	2000	13" diameter reel						
VS-15EWL06FNTR-M3	2000	2000	13 diameter reel						
VS-15AWL06FNTRL-M3	3000	3000	13" diameter reel						
VS-15EWL06FNTRL-M3	3000	3000							
VS-15AWL06FNTRR-M3	3000	3000	13" diameter reel						
VS-15EWL06FNTRR-M3	3000	3000	is ulaffieler reel						

LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95627							
Part marking information	www.vishay.com/doc?95176							
Packaging information	www.vishay.com/doc?95033							
SPICE model	www.vishay.com/doc?95372							

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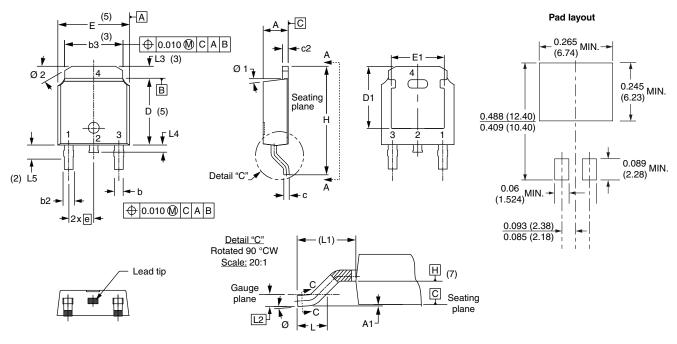


Outline Dimensions

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D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS	INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NUTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5]	Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3]	Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

- (6) Dimension b1 and c1 applied to base metal only
- ⁽⁷⁾ Datum A and B to be determined at datum plane H
- ⁽⁸⁾ Outline conforms to JEDEC[®] outline TO-252AA



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